



**PATENT**

Attorney Docket No.: ASC-025DV2C1

**IN THE UNITED STATES PATENT AND TRADEMARK OFFICE**

APPLICANT: Cheng et al.  
SERIAL NO.: 10/802,186                      GROUP NO.: 2813  
FILING DATE: March 17, 2004              EXAMINER: Monica D. Harrison  
TITLE: PROCESS FOR PRODUCING SEMICONDUCTOR ARTICLE  
USING GRADED EPITAXIAL GROWTH

Mail Stop Amendment  
Commissioner for Patents  
P.O. Box 1450  
Alexandria, VA 22313-1450

**SECOND PRELIMINARY AMENDMENT**

Prior to substantive examination, please enter the following amendments to the patent application identified above and consider the accompanying remarks.

Please amend the above-identified patent application as follows, without prejudice:

- **Amendments** to the specification begin on page 2 of this paper.
- **Remarks** begin on page 3 of this paper.